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- Industry-Standard Driver Replacement
- 25-ns Max Rise/Fall Times and 40-ns Max Propagation Delay – 1-nF Load, V<sub>CC</sub> = 14 V
- 2-A Peak Output Current, V<sub>CC</sub> = 14 V
- 5-µA Supply Current Input High or Low
- 4-V to 14-V Supply-Voltage Range; Internal Regulator Extends Range to 40 V (TPS2811, TPS2812, TPS2813)
- -40°C to 125°C Ambient-Temperature Operating Range

### description

The TPS28xx series of dual high-speed MOSFET drivers are capable of delivering peak currents of 2 A into highly capacitive loads. This performance is achieved with a design that inherently minimizes shoot-through current and consumes an order of magnitude less supply current than competitive products.

The TPS2811, TPS2812, and TPS2813 drivers include a regulator to allow operation with supply inputs between 14 V and 40 V. The regulator output can power other circuitry, provided power dissipation does

| TPS2811, TPS2812, TPS28<br>PACKA<br>(TOP VI | GES                 |
|---|---------------------|
| REG_IN [ 1                                  | 8 ] REG_OUT         |
| 1IN [ 2                                     | 7 ] 1OUT            |
| GND [ 3                                     | 6 ] V <sub>CC</sub> |
| 2IN [ 4                                     | 5 ] 2OUT            |
| TPS2814 D, P, AN<br>(TOP VI                 |                     |
| 1IN1 [ 1                                    | 8 ] GND             |
| 1IN2 [ 2                                    | 7 ] 1OUT            |
| 2IN1 [ 3                                    | 6 ] V <sub>CC</sub> |
| 2IN2 [ 4                                    | 5 ] 2OUT            |
| TPS2815 D, P, AN<br>(TOP VI                 |                     |
| 1IN1 [ 1                                    | 8] GND              |
| 1IN2 [ 2                                    | 7] 10UT             |
| 2IN1 [ 3                                    | 6] V <sub>CC</sub>  |
| 2IN2 [ 4                                    | 5] 20UT             |

not exceed package limitations. When the regulator is not required, REG\_IN and REG\_OUT can be left disconnected or both can be connected to  $V_{CC}$  or GND.

The TPS2814 and the TPS2815 have 2-input gates that give the user greater flexibility in controlling the MOSFET. The TPS2814 has AND input gates with one inverting input. The TPS2815 has dual-input NAND gates.

TPS281x series drivers, available in 8-pin PDIP, SOIC, and TSSOP packages operate over a ambient temperature range of –40°C to 125°C.

| AVAILABLE OF HONS |                       |  |                                  |                                  |                                     |  |  |  |
|-------------------|-----------------------|--|----------------------------------|----------------------------------|-------------------------------------|--|--|--|
|                   |                       |  | PACKAGED DEVICES                 |                                  |                                     |  |  |  |
|                   | INTERNAL<br>REGULATOR | LOGIC FUNCTION   | SMALL<br>OUTLINE<br>(D)          | PLASTIC<br>DIP<br>(P)            | TSSOP (PW)                          |  |  |  |
| -40°C             | Yes                   | Dual inverting drivers<br>Dual noninverting drivers<br>One inverting and one noninverting driver | TPS2811D<br>TPS2812D<br>TPS2813D | TPS2811P<br>TPS2812P<br>TPS2813P | TPS2811PW<br>TPS2812PW<br>TPS2813PW |  |  |  |
| to<br>125°C       | No                    | Dual 2-input AND drivers, one inverting input on each driver<br>Dual 2-input NAND drivers        | TPS2814D<br>TPS2815D             | TPS2814P<br>TPS2815P             | TPS2814PW<br>TPS2815PW              |  |  |  |

### AVAILABLE OPTIONS

The D package is available taped and reeled. Add R suffix to device type (e.g., TPS2811DR). The PW package is only available left-end taped and reeled and is indicated by the R suffix on the device type (e.g., TPS2811PWR).

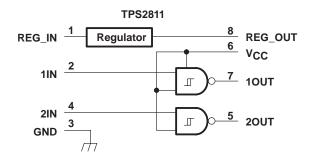


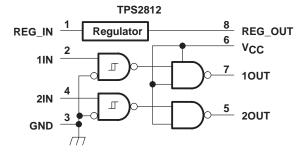
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

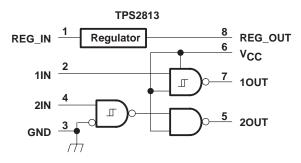


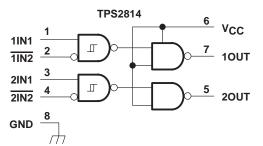
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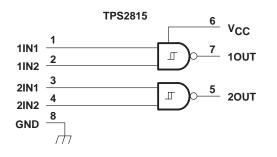
### functional block diagram

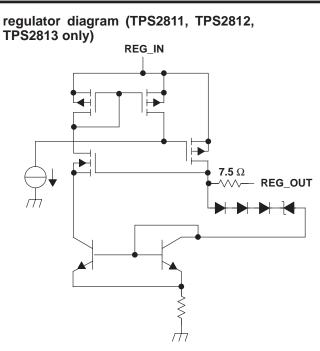




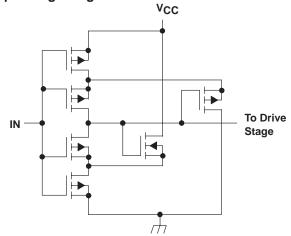




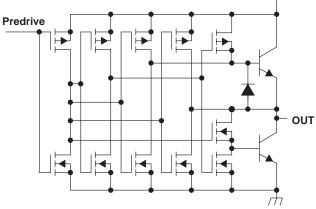




input stage diagram



output stage diagram



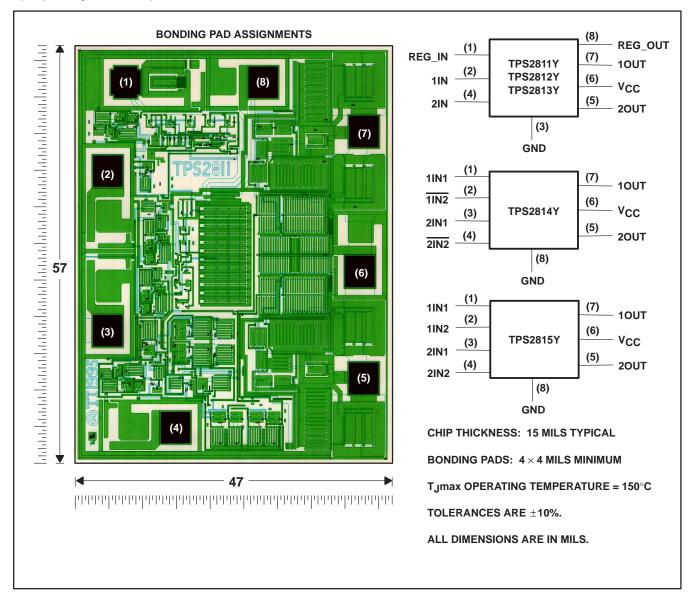
Vcc



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# **TPS28xxY** chip information

This chip, when properly assembled, displays characteristics similar to those of the TPS28xx. Thermal compression or ultrasonic bonding may be used on the doped aluminum bonding pads. The chip may be mounted with conductive epoxy or a gold-silicon preform.





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# **Terminal Functions**

### TPS2811, TPS2812, TPS2813

|                  |                                      | TERMINAL NUMBERS                        |                                     |                  |
|------------------|--------------------------------------|---|-------------------------------------|------------------|
| TERMINAL<br>NAME | TPS2811<br>Dual Inverting<br>Drivers | TPS2812<br>Dual Noninverting<br>Drivers | TPS2813<br>Complimentary<br>Drivers | DESCRIPTION      |
| REG_IN           | 1                                    | 1                                       | 1                                   | Regulator input  |
| 1IN              | 2                                    | 2                                       | 2                                   | Input 1          |
| GND              | 3                                    | 3                                       | 3                                   | Ground           |
| 2IN              | 4                                    | 4                                       | 4                                   | Input 2          |
| 20UT             | $5 = \overline{2IN}$                 | 5 = 2IN                                 | 5 = 2IN                             | Output 2         |
| VCC              | 6                                    | 6                                       | 6                                   | Supply voltage   |
| 10UT             | 7 = 11N                              | 7 = 1IN                                 | 7 = 11N                             | Output 1         |
| REG_OUT          | 8                                    | 8                                       | 8                                   | Regulator output |

### TPS2814, TPS2815

|                  | TERMINAL   | NUMBERS                      |                                  |
|------------------|--|------------------------------|----------------------------------|
| TERMINAL<br>NAME | TPS2814<br>Dual AND Drivers with Single<br>Inverting Input | TPS2815<br>Dual NAND Drivers | DESCRIPTION                      |
| 1IN1             | 1  | 1                            | Noninverting input 1 of driver 1 |
| 1IN2             | 2  | -                            | Inverting input 2 of driver 1    |
| 1IN2             | -  | 2                            | Noninverting input 2 of driver 1 |
| 2IN1             | 3  | 3                            | Noninverting input 1 of driver 2 |
| 2IN2             | 4  | -                            | Inverting input 2 of driver 2    |
| 2IN2             | -  | 4                            | Noninverting input 2 of driver 2 |
| 20UT             | $5 = 2IN1 \bullet \overline{2IN2}$                         | $5 = 2IN1 \bullet 2IN2$      | Output 2                         |
| VCC              | 6  | 6                            | Supply voltage                   |
| 10UT             | 7 = 1IN1 • 1IN2  | 7 = 11N1 • 11N2              | Output 1                         |
| GND              | 8  | 8                            | Ground                           |

### DISSIPATION RATING TABLE

| PACKAGE | $T_A \le 25^{\circ}C$<br>POWER RATING | DERATING FACTOR<br>ABOVE T <sub>A</sub> = 25°C | T <sub>A</sub> = 70°C<br>POWER RATING | T <sub>A</sub> = 85°C<br>POWER RATING |
|---------|---------------------------------------|--|---------------------------------------|---------------------------------------|
| Р       | 1090 mW                               | 8.74 mW/°C                                     | 697 mW                                | 566 mW                                |
| D       | 730 mW                                | 5.84 mW/°C                                     | 467 mW                                | 380 mW                                |
| PW      | 520 mW                                | 4.17 mW/°C                                     | 332 mW                                | 270 mW                                |



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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

|                                 | •                | •          | 0          | •                    | •       |                                  |
|---------------------------------|------------------|------------|------------|----------------------|---------|----------------------------------|
| Supply voltage, V <sub>CC</sub> |                  |            |            |                      |         | –0.3 V to 15 V                   |
| Regulator input voltage         | range, REG_      | IN         |            |                      |         | . $V_{CC}$ –0.3 V to 42 V        |
| Input voltage range, 1IN        | I, 2IŇ, 1IN1, 1  | IN2, 11N2, | 2IN1, 2IN2 | 2, <mark>2IN2</mark> |         | -0.3 V to V <sub>CC</sub> +0.5 V |
| Output voltage range, 1         | OUT, 2OUT .      |            |            |                      |         | $0.5 < V < V_{CC} + 0.5 V$       |
| Continuous regulator ou         | Itput current, I | REG_OUT    |            |                      |         | 25 mA                            |
| Continuous output curre         | ent, 10UT, 20    | UT         |            |                      |         | ±100 mA                          |
| Continuous total power          | dissipation .    |            |            |                      | See Dis | ssipation Rating Table           |
| Operating ambient temp          | perature range   | е, Тд      |            |                      |         | –40°C to 125°C                   |
| Storage temperature ra          |                  |            |            |                      |         |                                  |
| Lead temperature 1,6 m          |                  |            |            |                      |         |                                  |
|                                 |                  |            |            |                      |         |                                  |

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
NOTE 1: All voltages are with respect to device GND pin.

recommended operating conditions

|   | MIN  | MAX | UNIT |
|---|------|-----|------|
| Regulator input voltage range                               | 8    | 40  | V    |
| Supply voltage, V <sub>CC</sub>                             | 4    | 14  | V    |
| Input voltage, 1IN1, 1IN2, 1IN2, 2IN1, 2IN2, 2IN2, 1IN, 2IN | -0.3 | VCC | V    |
| Continuous regulator output current, REG_OUT                | 0    | 20  | mA   |
| Ambient temperature operating range                         | -40  | 125 | °C   |

# TPS28xx electrical characteristics over recommended operating ambient temperature range, $V_{CC}$ = 10 V, REG\_IN open for TPS2811/12/13, C<sub>L</sub> = 1 nF (unless otherwise noted)

### inputs

| PARAMETER   | TEST CONDITIONS          | MIN | TYP <sup>†</sup> | MAX  | UNIT |
|---|--------------------------|-----|------------------|--|------|
|   | $V_{CC} = 5 V$           |     | 3.3              | MAX<br>4<br>9<br>13<br>13<br>13<br>13  | V    |
| Positive-going input threshold voltage                                      | $V_{CC} = 10 V$          |     | 5.8              | 9  | V    |
|   | $V_{CC} = 14 V$          |     | 8.3              | 3.3     4       5.8     9       8.3     13       1.6     4.2       6.2     1.6       0.2     1 | V    |
|   | $V_{CC} = 5 V$           | 1   | 1.6              |  | V    |
| Negative-going input threshold voltage                                      | V <sub>CC</sub> = 10 V   | 1   | 4.2              | 5.8     9       8.3     13       1.6     4.2       6.2     1.6       0.2     1                 | V    |
| Negative-going input threshold voltage<br>Input hysteresis<br>Input current | $V_{CC} = 14 V$          | 1   | 6.2              |  | V    |
| Input hysteresis  | $V_{CC} = 5 V$           |     | 1.6              |  | V    |
| Input current   | Inputs = 0 V or $V_{CC}$ | -1  | 0.2              | 1  | μΑ   |
| Input capacitance   |                          |     | 5                | 10   | pF   |

<sup>†</sup> Typicals are for  $T_A = 25^{\circ}C$  unless otherwise noted.

### outputs

| PARAMETER  | TEST CONDITIONS          | MIN  | TYP† | MAX  | UNIT |
|--|--------------------------|------|------|------|------|
|  | $I_{O} = -1 \text{ mA}$  | 9.75 | 9.9  |      | V    |
| High-level output voltage  | I <sub>O</sub> = -100 mA | 8    | 9.1  |      | V    |
|  | I <sub>O</sub> = 1 mA    |      | 0.18 | 0.25 | V    |
| High-level output voltage Low-level output voltage Peak output current | I <sub>O</sub> = 100 mA  |      | 1    | 2    | V    |
| Peak output current  | V <sub>CC</sub> = 10 V   |      | 2    |      | А    |

<sup>†</sup> Typicals are for  $T_A = 25^{\circ}C$  unless otherwise noted.



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### regulator (TPS2811/2812/2813 only)

| PARAMETER                 | TEST CONI                                  | DITIONS                       | MIN | TYP† | MAX | UNIT |
|---------------------------|--|-------------------------------|-----|------|-----|------|
| Output voltage            | $14 \le \text{REG}_{IN} \le 40 \text{ V},$ | $0 \le I_O \le 20 \text{ mA}$ | 10  | 11.5 | 13  | V    |
| Output voltage in dropout | I <sub>O</sub> = 10 mA,                    | REG_IN = 10 V                 | 9   | 9.6  |     | V    |

 $\dagger$  Typicals are for  $T_A$  = 25°C unless otherwise noted.

### supply current

| PARAMETER                           | TEST CONDITIONS             |  | TYP† | MAX | UNIT |
|-------------------------------------|-----------------------------|--|------|-----|------|
| Supply current into V <sub>CC</sub> | Inputs high or low          |  | 0.2  | 5   | μΑ   |
| Supply current into REG_IN          | REG_IN = 20 V, REG_OUT open |  | 40   | 100 | μΑ   |

<sup>†</sup> Typicals are for  $T_A = 25^{\circ}C$  unless otherwise noted.

# TPS28xxY electrical characteristics at T<sub>A</sub> = 25°C, V<sub>CC</sub> = 10 V, REG\_IN open for TPS2811/12/13, C<sub>L</sub> = 1 nF (unless otherwise noted)

### inputs

| PARAMETER  | TEST CONDITIONS                       | MIN TYP   | MAX | UNIT |
|--|---------------------------------------|---|-----|------|
|  | $V_{CC} = 5 V$                        | 3.3   |     | V    |
| Positive-going input threshold voltage                                 | V <sub>CC</sub> = 10 V                | 5.8   |     | V    |
|  | $V_{CC} = 14 V$                       | 8.2   |     | V    |
|  | $V_{CC} = 5 V$                        | 3.3         5.8         8.2         1.6         3.3         4.2         1.2         0.2 | V   |      |
| egative-going input threshold voltage<br>put hysteresis<br>put current | V <sub>CC</sub> = 10 V                | 3.3   |     | V    |
|  | $V_{CC} = 14 V$                       | 4.2   |     | V    |
| Input hysteresis   | $V_{CC} = 5 V$                        | 1.2   |     | V    |
| Input current  | Inputs = $0 \vee \text{or} \vee_{CC}$ | 0.2   |     | μA   |
| Input capacitance  |                                       | 5   |     | pF   |

### outputs

| PARAMETER                   | TEST CONDITIONS          | MIN TYP MAX | UNIT |
|-----------------------------|--------------------------|-------------|------|
|                             | $I_{O} = -1 \text{ mA}$  | 9.9         | V    |
| High-level output voltage   | I <sub>O</sub> = -100 mA | 9.1         | V    |
| Level evel evel and the set | I <sub>O</sub> = 1 mA    | 0.18        | V    |
| Low-level output voltage    | I <sub>O</sub> = 100 mA  | 1           | V    |
| Peak output current         | V <sub>CC</sub> = 10.5 V | 2           | А    |

### regulator (TPS2811, 2812, 2813)

| PARAMETER                 | TEST COND                                  | MIN                           | TYP | MAX  | UNIT |   |
|---------------------------|--|-------------------------------|-----|------|------|---|
| Output voltage            | $14 \le \text{REG}_{IN} \le 40 \text{ V},$ | $0 \le I_O \le 20 \text{ mA}$ |     | 11.5 |      | V |
| Output voltage in dropout | I <sub>O</sub> = 10 mA,                    | REG_IN = 10 V                 |     | 9.6  |      | V |

### power supply current

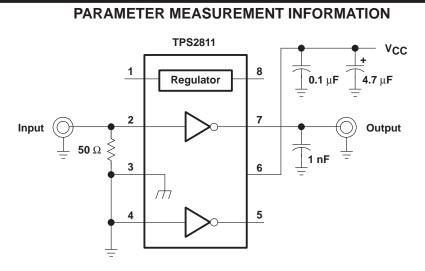
| PARAMETER                           | TEST CONDITIONS             | MIN | TYP | MAX | UNIT |
|-------------------------------------|-----------------------------|-----|-----|-----|------|
| Supply current into V <sub>CC</sub> | Inputs high or low          |     | 0.2 |     | μA   |
| Supply current into REG_IN          | REG_IN = 20 V, REG_OUT open |     | 40  |     | μΑ   |



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switching characteristics for all devices over recommended operating ambient temperature range, REG\_IN open for TPS2811/12/13,  $C_L = 1$  nF (unless otherwise specified)

|                  | PARAMETER                                | TEST CONDITIONS        | MIN | TYP | MAX | UNIT                   |
|------------------|--|------------------------|-----|-----|-----|------------------------|
|                  |  | V <sub>CC</sub> = 14 V |     | 14  | 25  | UNIT<br>ns<br>ns<br>ns |
| tr               | Rise time                                | V <sub>CC</sub> = 10 V |     | 15  | 30  | ns                     |
|                  |  | $V_{CC} = 5 V$         |     | 20  | 35  |                        |
|                  |  | V <sub>CC</sub> = 14 V |     | 15  | 25  |                        |
| t <sub>f</sub>   | Fall time                                | V <sub>CC</sub> = 10 V |     | 15  | 30  | ns                     |
|                  |  | $V_{CC} = 5 V$         |     | 18  | 35  |                        |
|                  |  | V <sub>CC</sub> = 14 V |     | 25  | 40  | ns                     |
| <sup>t</sup> PHL | Prop delay time high-to-low-level output | V <sub>CC</sub> = 10 V |     | 25  | 45  |                        |
|                  |  | $V_{CC} = 5 V$         |     | 34  | 50  |                        |
|                  |  | V <sub>CC</sub> = 14 V |     | 24  | 40  | ns                     |
| <sup>t</sup> PLH | Prop delay time low-to-high-level output | V <sub>CC</sub> = 10 V |     | 26  | 45  |                        |
|                  |  | $V_{CC} = 5 V$         |     | 36  | 50  |                        |



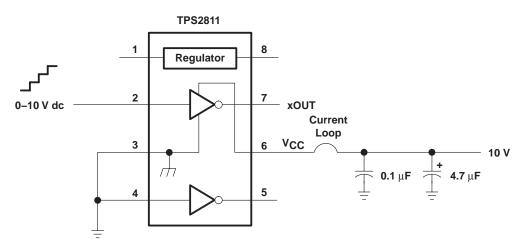
NOTE A: Input rise and fall times should be  $\leq 10$  ns for accurate measurement of ac parameters.

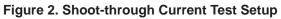
### Figure 1. Test Circuit For Measurement of Switching Characteristics



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## PARAMETER MEASUREMENT INFORMATION





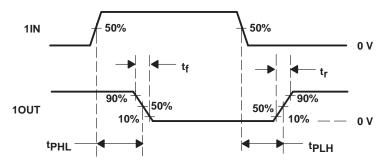


Figure 3. Typical Timing Diagram (TPS2811)

# **TYPICAL CHARACTERISTICS**

### **Tables of Characteristics Graphs and Application Information**

### typical characteristics

| PARAMETER                   | vs PARAMETER 2             | FIGURE | PAGE |
|-----------------------------|----------------------------|--------|------|
| Rise time                   | Supply voltage             | 4      | 10   |
| Fall time                   | Supply voltage             | 5      | 10   |
| Propagation delay time      | Supply voltage             | 6, 7   | 10   |
|                             | Supply voltage             | 8      | 11   |
| Supply current              | Load capacitance           | 9      | 11   |
|                             | Ambient temperature        | 10     | 11   |
| Input threshold voltage     | Supply voltage             | 11     | 11   |
| Regulator output voltage    | Regulator input voltage    | 12, 13 | 12   |
| Regulator quiescent current | Regulator input voltage    | 14     | 12   |
| Peak source current         | Supply voltage             | 15     | 12   |
| Peak sink current           | Supply voltage             | 16     | 13   |
| Sheet through current       | Input voltage, high-to-low | 17     | 13   |
| Shoot-through current       | Input voltage, low-to-high | 18     | 13   |



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# **TYPICAL CHARACTERISTICS**

### Tables of Characteristics Graphs and Application Information (Continued)

### general applications

| PARAMETER   |          | vs PARAMETER 2 | FIGURE     | PAGE   |
|---|----------|----------------|------------|--------|
| Switching test circuits and application information |          |                | 19, 20     | 15     |
|   | <b>T</b> | Low-to-high    | 21, 23, 25 | 16, 17 |
| Voltage of 10UT vs 20UT                             | Time     | High-to-low    | 22, 24, 26 | 16, 17 |

### circuit for measuring paralleled switching characteristics

| PARAMETER   |          | vs PARAMETER 2 | FIGURE | PAGE |
|---|----------|----------------|--------|------|
| Switching test circuits and application information |          |                | 27     | 17   |
| Level with a second sector device as                | <b>T</b> | Low-to-high    | 28, 30 | 18   |
| Input voltage vs output voltage                     | Time     | High-to-low    | 29, 31 | 18   |

### Hex-1 to Hex-4 application information

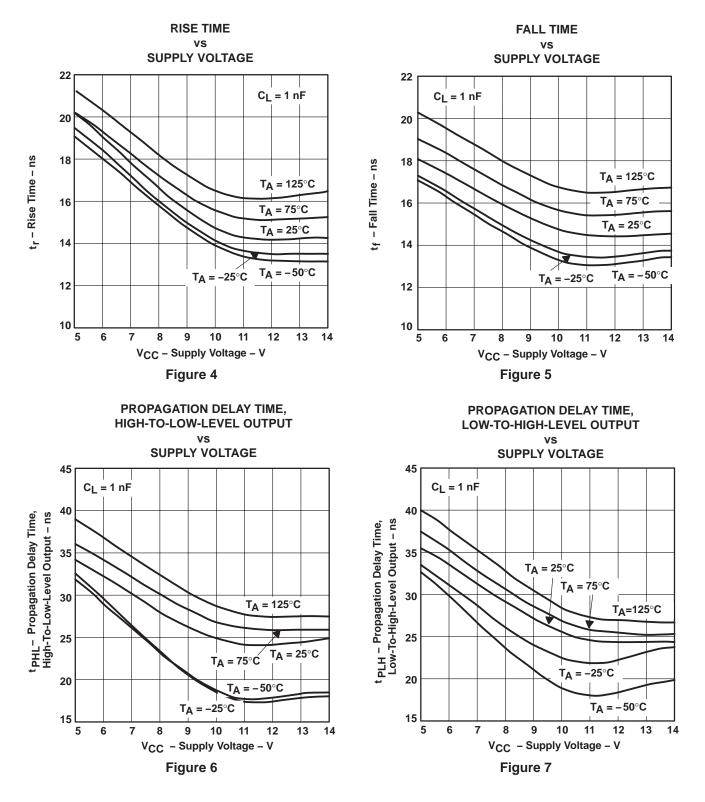
| PARAMETER   |      | vs PARAMETER 2            | FIGURE | PAGE |
|---|------|---------------------------|--------|------|
| Driving test circuit and application information        |      |                           | 32     | 19   |
|   |      | Hex-1 size                | 33     | 20   |
|   |      | Hex-2 size                | 36     | 20   |
| Drain-source voltage vs drain current                   | Time | Hex-3 size                | 39     | 21   |
|   |      | Hex-4 size                | 41     | 22   |
|   |      | Hex-4 size parallel drive | 45     | 23   |
|   |      | Hex-1 size                | 34     | 20   |
|   |      | Hex-2 size                | 37     | 21   |
| Drain-source voltage vs gate-source voltage at turn-on  | Time | Hex-3 size                | 40     | 21   |
|   |      | Hex-4 size                | 43     | 22   |
|   |      | Hex-4 size parallel drive | 46     | 23   |
|   |      | Hex-1 size                | 35     | 20   |
|   |      | Hex-2 size                | 38     | 21   |
| Drain-source voltage vs gate-source voltage at turn-off | Time | Hex-3 size                | 42     | 22   |
|   |      | Hex-4 size                | 44     | 22   |
|   |      | Hex-4 size parallel drive | 47     | 23   |

### synchronous buck regulator application

| PARAMETER  |      | vs PARAMETER 2 | FIGURE     | PAGE   |
|--|------|----------------|------------|--------|
| 3.3-V 3-A Synchronous-Rectified Buck Regulator Circuit |      |                | 48         | 24     |
| Q1 drain voltage vs gate voltage at turn-on            |      |                | 49         | 26     |
| Q1 drain voltage vs gate voltage at turn-off           |      |                | 50         | 26     |
| Q1 drain voltage vs Q2 gate-source voltage             | Time |                | 51, 52, 53 | 26, 27 |
|  |      | 3 A            | 54         | 27     |
| Output ripple voltage vs inductor current              |      | 5 A            | 55         | 27     |



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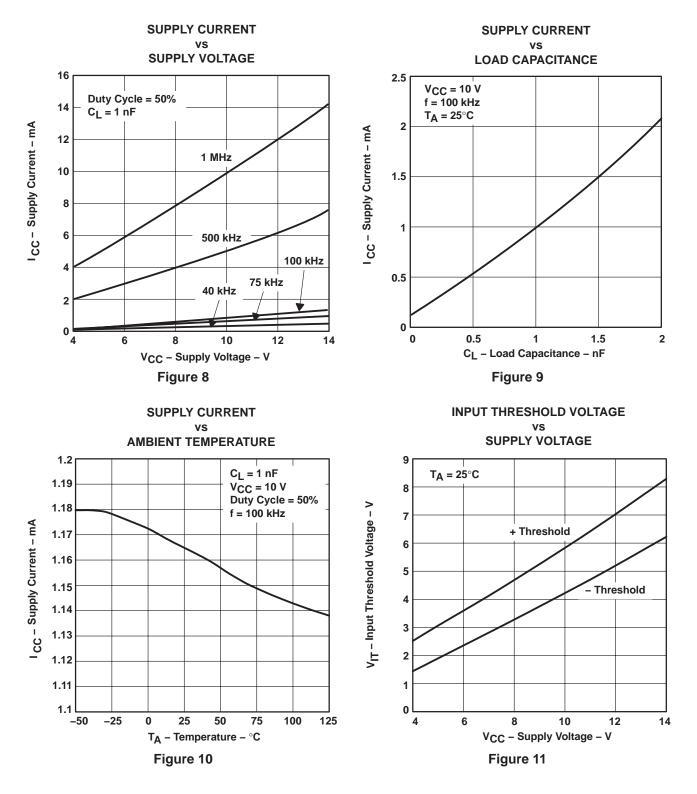


**TYPICAL CHARACTERISTICS** 



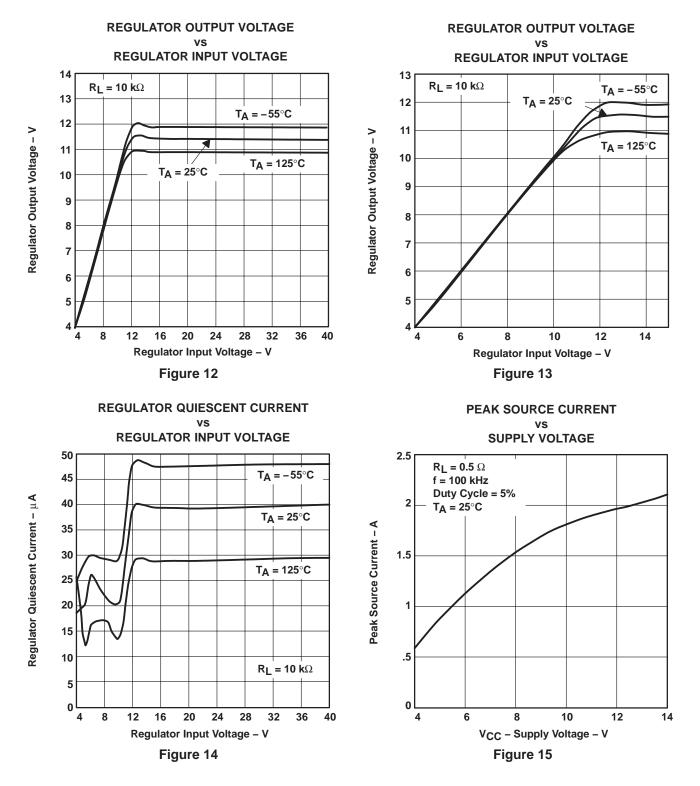
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### **TYPICAL CHARACTERISTICS**





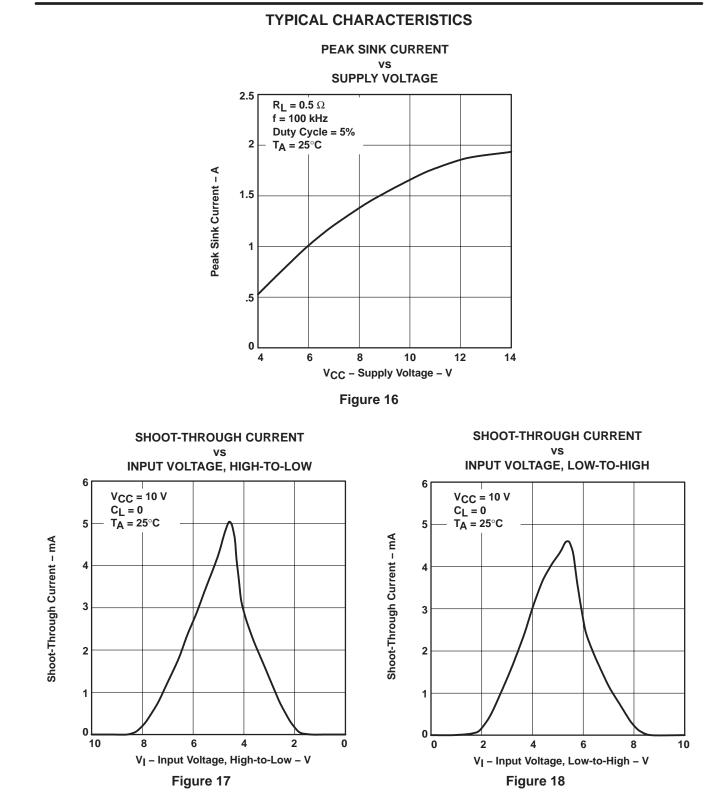
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# **TYPICAL CHARACTERISTICS**



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# **APPLICATION INFORMATION**

The TPS2811, TPS2812 and TPS2813 circuits each contain one regulator and two MOSFET drivers. The regulator can be used to limit  $V_{CC}$  to between 10 V and 13 V for a range of input voltages from 14 V to 40 V, while providing up to 20 mA of dc drive. The TPS2814 and TPS2815 both contain two drivers, each of which has two inputs. The TPS2811 has inverting drivers, the TPS2812 has noninverting drivers, and the TPS2813 has one inverting and one noninverting driver. The TPS2814 is a dual 2-input AND driver with one inverting input on each driver, and the TPS2815 is a dual 2-input NAND driver. These MOSFET drivers are capable of supplying up to 2.1 A or sinking up to 1.9 A (see Figures 15 and 16) of instantaneous current to n-channel or p-channel MOSFETs. The TPS2811 family of MOSFET drivers have very fast switching times combined with very short propagation delays. These features enhance the operation of today's high-frequency circuits.

The CMOS input circuit has a positive threshold of approximately 2/3 of  $V_{CC}$ , with a negative threshold of 1/3 of  $V_{CC}$ , and a very high input impedance in the range of  $10^9 \Omega$ . Noise immunity is also very high because of the Schmidt trigger switching. In addition, the design is such that the normal shoot-through current in CMOS (when the input is biased halfway between  $V_{CC}$  and ground) is limited to less than 6 mA. The limited shoot-through is evident in the graphs in Figures 17 and 18. The input stage shown in the functional block diagram better illustrates the way the front end works. The circuitry of the device is such that regardless of the rise and/or fall time of the input signal, the output signal will always have a fast transition speed; this basically isolates the waveforms at the input from the output. Therefore, the specified switching times are not affected by the slopes of the input waveforms.

The basic driver portion of the circuits operate over a supply voltage range of 4 V to 14 V with a maximum bias current of 5  $\mu$ A. Each driver consists of a CMOS input and a buffered output with a 2-A instantaneous drive capability. They have propagation delays of less than 30 ns and rise and fall times of less than 20 ns each. Placing a 0.1- $\mu$ F ceramic capacitor between V<sub>CC</sub> and ground is recommended; this will supply the instantaneous current needed by the fast switching and high current surges of the driver when it is driving a MOSFET.

The output circuit is also shown in the functional block diagram. This driver uses a unique combination of a bipolar transistor in parallel with a MOSFET for the ability to swing from  $V_{CC}$  to ground while providing 2 A of instantaneous driver current. This unique parallel combination of bipolar and MOSFET output transistors provides the drive required at  $V_{CC}$  and ground to guarantee turn-off of even low-threshold MOSFETs. Typical bipolar-only output devices don't easily approach  $V_{CC}$  or ground.

The regulator, included in the TPS2811, TPS2812 and TPS2813, has an input voltage range of 14 V to 40 V. It produces an output voltage of 10 V to 13 V and is capable of supplying from 0 to 20 mA of output current. In grounded source applications, this extends the overall circuit operation to 40 V by clamping the driver supply voltage (V<sub>CC</sub>) to a safe level for both the driver and the MOSFET gate. The bias current for full operation is a maximum of 150  $\mu$ A. A 0.1- $\mu$ F capacitor connected between the regulator output and ground is required to ensure stability. For transient response, an additional 4.7- $\mu$ F electrolytic capacitor on the output and a 0.1- $\mu$ F ceramic capacitor on the input will optimize the performance of this circuit. When the regulator is not in use, it can be left open at both the input and the output, or the input can be shorted to the output and tied to either the V<sub>CC</sub> or the ground pin of the chip.

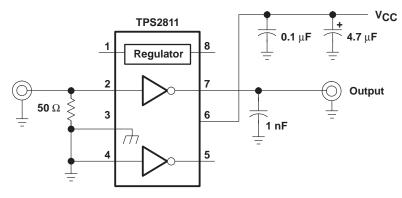


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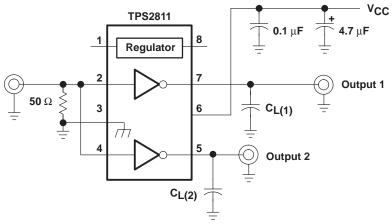
### **APPLICATION INFORMATION**

### matching and paralleling connections

Figures 21 and 22 show the delays for the rise and fall time of each channel. As can be seen on a 5-ns scale, there is very little difference between the two channels at no load. Figures 23 and 24 show the difference between the two channels for a 1-nF load on each output. There is a slight delay on the rising edge, but little or no delay on the falling edge. As an example of extreme overload, Figures 25 and 26 show the difference between the two channels, or two drivers in the package, each driving a 10-nF load. As would be expected, the rise and fall times are significantly slowed down. Figures 28 and 29 show the effect of paralleling the two channels and driving a 1-nF load. A noticeable improvement is evident in the rise and fall times of the output waveforms. Finally, Figures 30 and 31 show the two drivers being paralleled to drive the 10-nF load and as could be expected the waveforms are improved. In summary, the paralleling of the two drivers in a package enhances the capability of the drivers to handle a larger load. Because of manufacturing tolerances, it is not recommended to parallel drivers that are not in the same package.





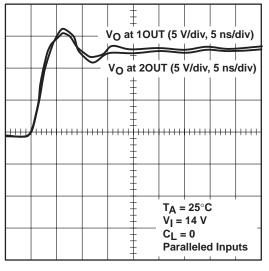


NOTE A: Input rise and fall times should be ≤10 ns for accurate measurement of ac parameters.

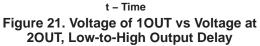
Figure 20. Test Circuit for Measuring Switching Characteristics with the Inputs Connected in Parallel

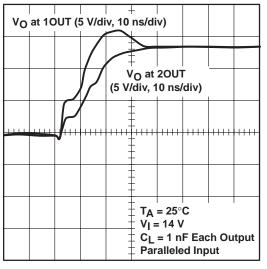


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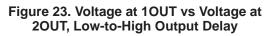


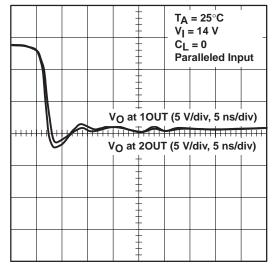


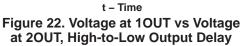


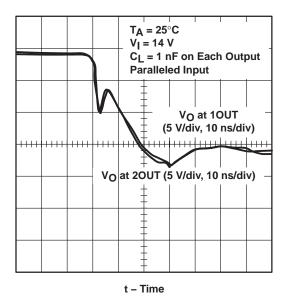


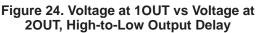
t – Time



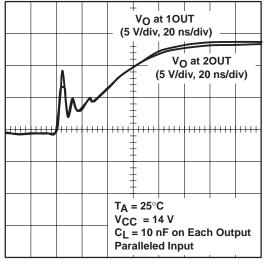




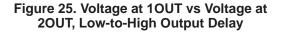


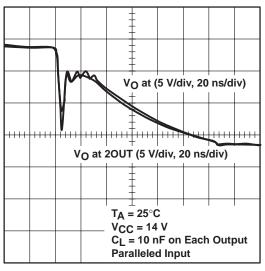


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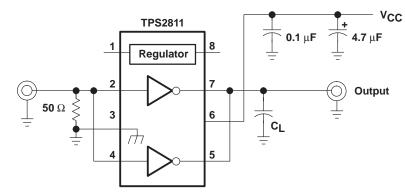
### t – Time





t – Time

Figure 26. Voltage at 10UT vs Voltage at 20UT, High-to-Low Output Delay



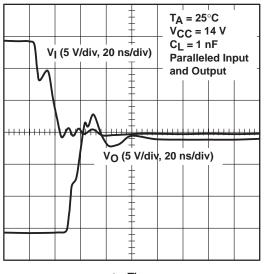
**APPLICATION INFORMATION** 

NOTE A: Input rise and fall times should be ≤10 ns for accurate measurement of ac parameters.

### Figure 27. Test Circuit for Measuring Paralleled Switching Characteristics



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### **APPLICATION INFORMATION**

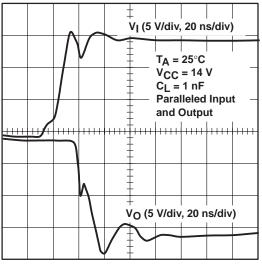
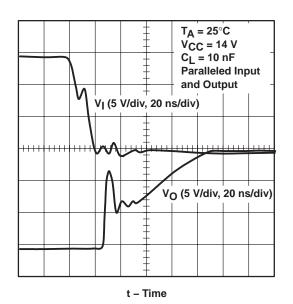




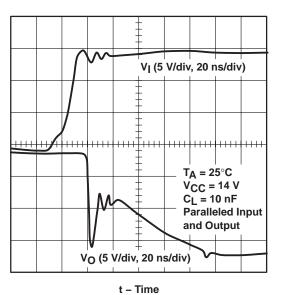
Figure 28. Input Voltage vs Output Voltage, Low-to-High Propagation Delay of Paralleled Drivers













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Figures 33 through 47 illustrate the performance of the TPS2811 driving MOSFETs with clamped inductive loads, similar to what is encountered in discontinuous-mode flyback converters. The MOSFETs that were tested range in size from Hex-1 to Hex-4, although the TPS28xx family is only recommended for Hex-3 or below.

The test circuit is shown in Figure 32. The layout rules observed in building the test circuit also apply to real applications. Decoupling capacitor C1 is a 0.1-µF ceramic device, connected between V<sub>CC</sub> and GND of the TPS2811, with short lead lengths. The connection between the driver output and the MOSFET gate, and between GND and the MOSFET source, are as short as possible to minimize inductance. Ideally, GND of the driver is connected directly to the MOSFET source. The tests were conducted with the pulse generator frequency set very low to eliminate the need for heat sinking, and the duty cycle was set to turn off the MOSFET when the drain current reached 50% of its rated value. The input voltage was adjusted to clamp the drain voltage at 80% of its rating.

As shown, the driver is capable of driving each of the Hex-1 through Hex-3 MOSFETs to switch in 20 ns or less. Even the Hex-4 is turned on in less than 20 ns. Figures 45, 46 and 47 show that paralleling the two drivers in a package enhances the gate waveforms and improves the switching speed of the MOSFET. Generally, one driver is capable of driving up to a Hex-4 size. The TPS2811 family is even capable of driving large MOSFETs that have a low gate charge.

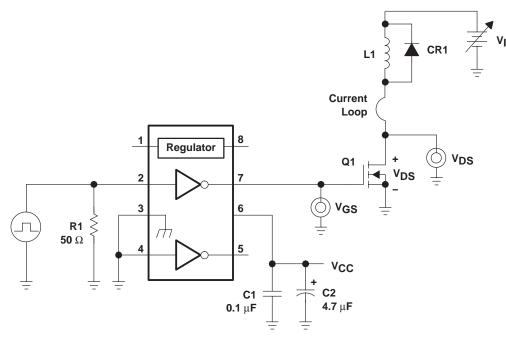
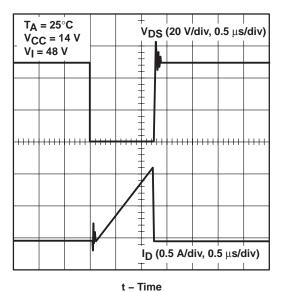


Figure 32. TPS2811 Driving Hex-1 through Hex-4 Devices



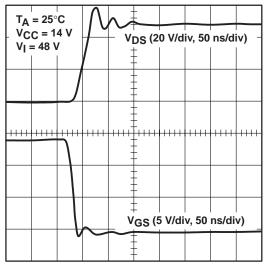
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t – Time

Figure 35. Drain-Source Voltage vs Gate-Source Voltage, at Turn-off, TPS2811 Driving an IRFD014 (Hex-1 Size)

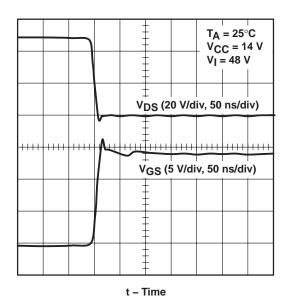
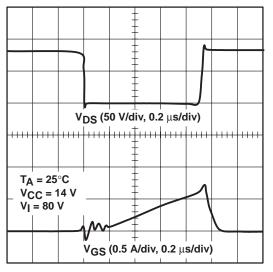
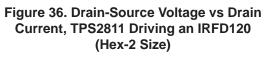


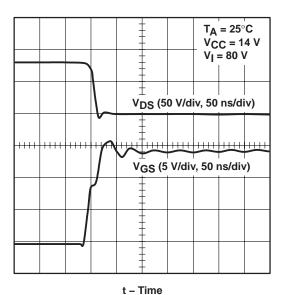
Figure 34. Drain-Source Voltage vs Gate-Source Voltage, at Turn-on, TPS2811 Driving an IRFD014 (Hex-1 Size)



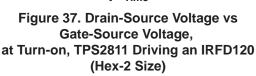


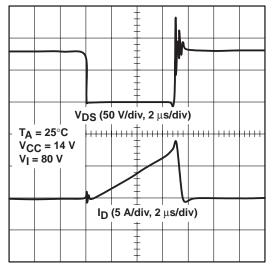


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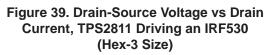


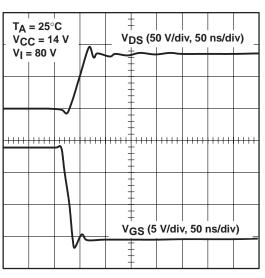
### **APPLICATION INFORMATION**





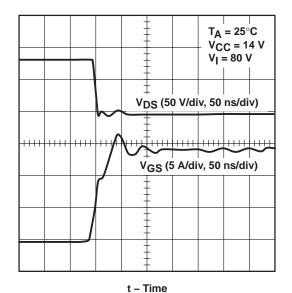
t – Time

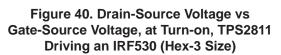




t – Time

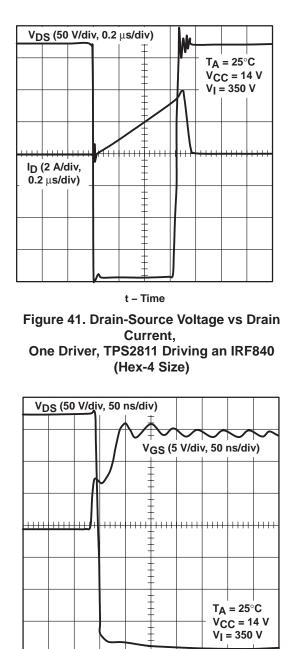
Figure 38. Drain-Source Voltage vs Gate-Source Voltage, at Turn-off, TPS2811 Driving an IRFD120 (Hex-2 Size)



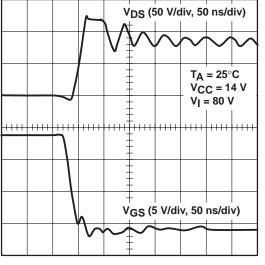




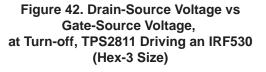
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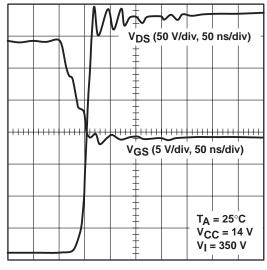




Figure 44. Drain-Source Voltage vs Gate-Source Voltage, at Turn-off, One Driver, TPS2811 Driving an IRF840 (Hex-4 Size)



Figure 43. Drain-Source Voltage vs Gate-Source Voltage, at Turn-on, One Driver, TPS2811 Driving an IRF840 (Hex-4 Size)

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# V<sub>DS</sub> (50 V/div, 0.2 μs/div)

t – Time

Figure 45. Drain-Source Voltage vs Drain Current, Parallel Drivers, TPS2811 Driving an IRF840 (Hex-4 Size)

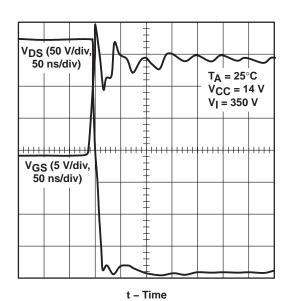
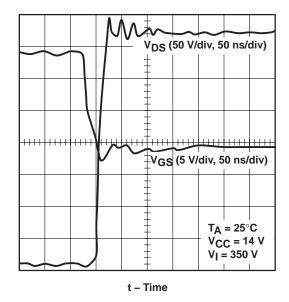


Figure 46. Drain-Source Voltage vs Gate-Source Voltage, at Turn-on, Parallel Drivers, TPS2811 Driving an IRF840 (Hex-4 Size)



**APPLICATION INFORMATION** 





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## **APPLICATION INFORMATION**

### synchronous buck regulator

Figure 48 is the schematic for a 100-kHz synchronous-rectified buck converter implemented with a TL5001 pulse-width-modulation (PWM) controller and a TPS2812 driver. The bill of materials is provided in Table 1. The converter operates over an input range from 5.5 V to 12 V and has a 3.3-V output capable of supplying 3 A continuously and 5 A during load surges. The converter achieves an efficiency of 90.6% at 3 A and 87.6% at 5 A. Figures 49 and 50 show the power switch switching performance. The output ripple voltage waveforms are documented in Figures 54 and 55.

The TPS2812 drives both the power switch, Q2, and the synchronous rectifier, Q1. Large shoot-through currents, caused by power switch and synchronous rectifier remaining on simultaneously during the transitions, are prevented by small delays built into the drive signals, using CR2, CR3, R11, R12, and the input capacitance of the TPS2812. These delays allow the power switch to turn off before the synchronous rectifier turns on and vice versa. Figure 51 shows the delay between the drain of Q2 and the gate of Q1; expanded views are provided in Figures 52 and 53.

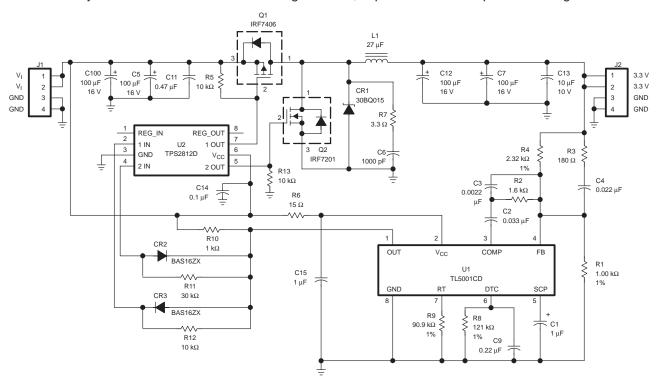


Figure 48. 3.3-V 3-A Synchronous-Rectified Buck Regulator Circuit

**NOTE:** If the parasitics of the external circuit cause the voltage to violate the Absolute Maximum Rating for the Output pins, Schottky diodes should be added from ground to output and from output to Vcc.



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## **APPLICATION INFORMATION**

| REFERENCE     | DESCRIPTION                              | VENDO                    | R            |  |  |  |  |  |  |  |  |
|---------------|--|--------------------------|--------------|--|--|--|--|--|--|--|--|
| U1            | TL5001CD, PWM                            | Texas Instruments,       | 972-644-5580 |  |  |  |  |  |  |  |  |
| U2            | TPS2812D, N.I. MOSFET Driver             | Texas Instruments,       | 972-644-5580 |  |  |  |  |  |  |  |  |
| CR1           | 3 A, 15 V, Schottky, 30BQ015             | International Rectifier, | 310-322-3331 |  |  |  |  |  |  |  |  |
| CR2,CR3       | Signal Diode, BAS16ZX                    | Zetex,                   | 516-543-7100 |  |  |  |  |  |  |  |  |
| C1            | 1 µF, 16 V, Tantalum                     |                          |              |  |  |  |  |  |  |  |  |
| C2            | 0.033 μF, 50 V                           |                          |              |  |  |  |  |  |  |  |  |
| C3            | 0.0022 μF, 50 V                          |                          |              |  |  |  |  |  |  |  |  |
| C4            | 0.022 μF, 50 V                           |                          |              |  |  |  |  |  |  |  |  |
| C5,C7,C10,C12 | 100 μF, 16 V, Tantalum, TPSE107M016R0100 | AVX,                     | 800-448-9411 |  |  |  |  |  |  |  |  |
| C6            | 1000 pF, 50 V                            |                          |              |  |  |  |  |  |  |  |  |
| C9            | 0.22 μF, 50 V                            |                          |              |  |  |  |  |  |  |  |  |
| C11           | 0.47 μF, 50 V, Z5U                       |                          |              |  |  |  |  |  |  |  |  |
| C13           | 10 μF, 10 V, Ceramic, CC1210CY5V106Z     | TDK,                     | 708-803-6100 |  |  |  |  |  |  |  |  |
| C14           | 0.1 μF, 50 V                             |                          |              |  |  |  |  |  |  |  |  |
| C15           | 1.0 μF, 50 V                             |                          |              |  |  |  |  |  |  |  |  |
| J1,J2         | 4-Pin Header                             |                          |              |  |  |  |  |  |  |  |  |
| L1            | 27 μH, 3 A/5 A, SML5040                  | Nova Magnetics, Inc.,    | 972-272-8287 |  |  |  |  |  |  |  |  |
| Q1            | IRF7406, P-FET                           | International Rectifier, | 310-322-3331 |  |  |  |  |  |  |  |  |
| Q2            | IRF7201, N-FET                           | International Rectifier, | 310-322-3331 |  |  |  |  |  |  |  |  |
| R1            | 1.00 kΩ, 1%                              |                          |              |  |  |  |  |  |  |  |  |
| R2            | 1.6 kΩ                                   |                          |              |  |  |  |  |  |  |  |  |
| R3            | 180 Ω                                    |                          |              |  |  |  |  |  |  |  |  |
| R4            | 2.32 kΩ, 1 %                             |                          |              |  |  |  |  |  |  |  |  |
| R5,R12,R13    | 10 kΩ                                    |                          |              |  |  |  |  |  |  |  |  |
| R6            | 15 Ω                                     |                          |              |  |  |  |  |  |  |  |  |
| R7            | 3.3 Ω                                    |                          |              |  |  |  |  |  |  |  |  |
| R8            | 121 kΩ, 1%                               |                          |              |  |  |  |  |  |  |  |  |
| R9            | 90.9 kΩ, 1%                              |                          |              |  |  |  |  |  |  |  |  |
| R10           | 1 kΩ                                     |                          |              |  |  |  |  |  |  |  |  |
| R11           | 30 kΩ                                    |                          |              |  |  |  |  |  |  |  |  |

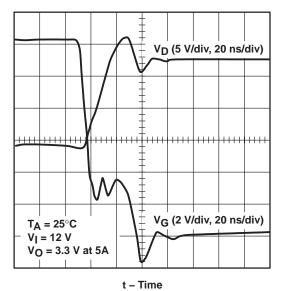
### Table 1. Bill of Materials, 3.3-V, 3-A Synchronous-Rectified Buck Converter

NOTES: 2. Unless otherwise specified, capacitors are X7R ceramics.

3. Unless otherwise specified, resistors are 5%, 1/10 W.

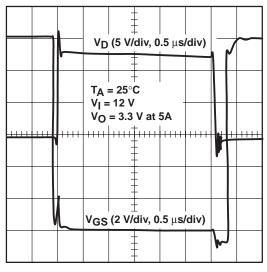


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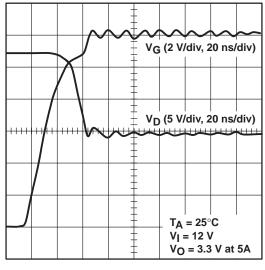
### **APPLICATION INFORMATION**





t – Time

Figure 51. Q1 Drain Voltage vs Q2 Gate-Source Voltage







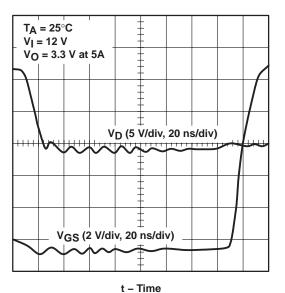
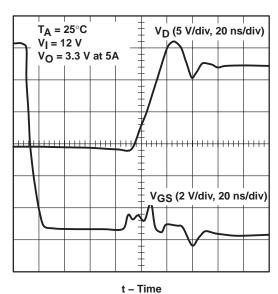


Figure 52. Q1 Drain Voltage vs Q2

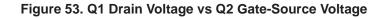
Gate-Source Voltage

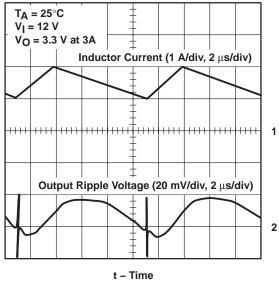


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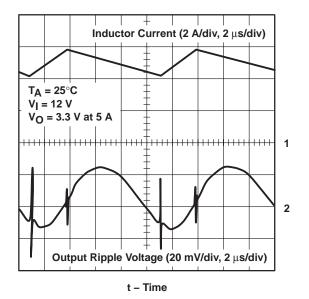


Figure 55. Output Ripple Voltage vs Inductor Current, at 5 A





24-Aug-2018

# PACKAGING INFORMATION

| Orderable Device | Status | Package Type | •       | Pins | •    | Eco Plan                   | Lead/Ball Finish | MSL Peak Temp      | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|------|----------------------------|------------------|--------------------|--------------|----------------|---------|
|                  | (1)    |              | Drawing |      | Qty  | (2)                        | (6)              | (3)                |              | (4/5)          |         |
| TPS2811D         | ACTIVE | SOIC         | D       | 8    | 75   | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM |              | 2811           | Samples |
| TPS2811DR        | ACTIVE | SOIC         | D       | 8    | 2500 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | 2811           | Samples |
| TPS2811P         | ACTIVE | PDIP         | Р       | 8    | 50   | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | N / A for Pkg Type |              | TPS2811P       | Samples |
| TPS2811PW        | ACTIVE | TSSOP        | PW      | 8    | 150  | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM |              | PS2811         | Samples |
| TPS2811PWR       | ACTIVE | TSSOP        | PW      | 8    | 2000 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM |              | PS2811         | Samples |
| TPS2812D         | ACTIVE | SOIC         | D       | 8    | 75   | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | 2812           | Samples |
| TPS2812DR        | ACTIVE | SOIC         | D       | 8    | 2500 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM |              | 2812           | Samples |
| TPS2812DRG4      | ACTIVE | SOIC         | D       | 8    | 2500 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM |              | 2812           | Samples |
| TPS2812P         | ACTIVE | PDIP         | Р       | 8    | 50   | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | N / A for Pkg Type |              | TPS2812P       | Samples |
| TPS2812PWR       | ACTIVE | TSSOP        | PW      | 8    | 2000 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM |              | PS2812         | Samples |
| TPS2813D         | ACTIVE | SOIC         | D       | 8    | 75   | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | 2813           | Samples |
| TPS2813DR        | ACTIVE | SOIC         | D       | 8    | 2500 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | 2813           | Samples |
| TPS2813P         | ACTIVE | PDIP         | Р       | 8    | 50   | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | N / A for Pkg Type | -40 to 125   | TPS2813P       | Samples |
| TPS2813PWR       | ACTIVE | TSSOP        | PW      | 8    | 2000 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | PS2813         | Samples |
| TPS2814D         | ACTIVE | SOIC         | D       | 8    | 75   | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM |              | 2814           | Samples |
| TPS2814DR        | ACTIVE | SOIC         | D       | 8    | 2500 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | 2814           | Samples |
| TPS2814DRG4      | ACTIVE | SOIC         | D       | 8    | 2500 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | 2814           | Samples |



24-Aug-2018

| Orderable Device | Status | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish | MSL Peak Temp      | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|------------------|--------|--------------|--------------------|------|----------------|----------------------------|------------------|--------------------|--------------|-------------------------|---------|
| TPS2814P         | ACTIVE | PDIP         | Р                  | 8    | 50             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | N / A for Pkg Type |              | TPS2814P                | Samples |
| TPS2814PE4       | ACTIVE | PDIP         | Р                  | 8    | 50             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | N / A for Pkg Type |              | TPS2814P                | Samples |
| TPS2814PW        | ACTIVE | TSSOP        | PW                 | 8    | 150            | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM |              | PS2814                  | Samples |
| TPS2814PWR       | ACTIVE | TSSOP        | PW                 | 8    | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | PS2814                  | Samples |
| TPS2815D         | ACTIVE | SOIC         | D                  | 8    | 75             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM |              | 2815                    | Samples |
| TPS2815DG4       | ACTIVE | SOIC         | D                  | 8    | 75             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM |              | 2815                    | Samples |
| TPS2815DR        | ACTIVE | SOIC         | D                  | 8    | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | 2815                    | Samples |
| TPS2815P         | ACTIVE | PDIP         | Р                  | 8    | 50             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | N / A for Pkg Type |              | TPS2815P                | Samples |
| TPS2815PWR       | ACTIVE | TSSOP        | PW                 | 8    | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM |              | PS2815                  | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



# PACKAGE OPTION ADDENDUM

24-Aug-2018

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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### OTHER QUALIFIED VERSIONS OF TPS2811 :

Automotive: TPS2811-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

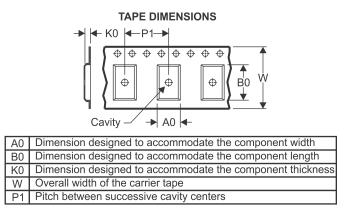
# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| Device     | Package<br>Type | Package<br>Drawing | Pins | SPQ  | Reel<br>Diameter | Reel<br>Width | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|------------|-----------------|--------------------|------|------|------------------|---------------|------------|------------|------------|------------|-----------|------------------|
|            |                 | -                  |      |      | (mm)             | W1 (mm)       |            |            |            | . ,        | . ,       |                  |
| TPS2811DR  | SOIC            | D                  | 8    | 2500 | 330.0            | 12.4          | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| TPS2811DR  | SOIC            | D                  | 8    | 2500 | 330.0            | 12.4          | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| TPS2811PWR | TSSOP           | PW                 | 8    | 2000 | 330.0            | 12.4          | 7.0        | 3.6        | 1.6        | 8.0        | 12.0      | Q1               |
| TPS2812DR  | SOIC            | D                  | 8    | 2500 | 330.0            | 12.4          | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| TPS2812DR  | SOIC            | D                  | 8    | 2500 | 330.0            | 12.4          | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| TPS2812PWR | TSSOP           | PW                 | 8    | 2000 | 330.0            | 12.4          | 7.0        | 3.6        | 1.6        | 8.0        | 12.0      | Q1               |
| TPS2813DR  | SOIC            | D                  | 8    | 2500 | 330.0            | 12.4          | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| TPS2813DR  | SOIC            | D                  | 8    | 2500 | 330.0            | 12.4          | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| TPS2813PWR | TSSOP           | PW                 | 8    | 2000 | 330.0            | 12.4          | 7.0        | 3.6        | 1.6        | 8.0        | 12.0      | Q1               |
| TPS2814DR  | SOIC            | D                  | 8    | 2500 | 330.0            | 12.4          | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| TPS2814DR  | SOIC            | D                  | 8    | 2500 | 330.0            | 12.4          | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| TPS2814PWR | TSSOP           | PW                 | 8    | 2000 | 330.0            | 12.4          | 7.0        | 3.6        | 1.6        | 8.0        | 12.0      | Q1               |
| TPS2815DR  | SOIC            | D                  | 8    | 2500 | 330.0            | 12.4          | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| TPS2815PWR | TSSOP           | PW                 | 8    | 2000 | 330.0            | 12.4          | 7.0        | 3.6        | 1.6        | 8.0        | 12.0      | Q1               |

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# PACKAGE MATERIALS INFORMATION

24-Aug-2016



| *All dimensions are nominal |              |                 |      |      |             |            |             |
|-----------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device                      | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
| TPS2811DR                   | SOIC         | D               | 8    | 2500 | 340.5       | 338.1      | 20.6        |
| TPS2811DR                   | SOIC         | D               | 8    | 2500 | 367.0       | 367.0      | 38.0        |
| TPS2811PWR                  | TSSOP        | PW              | 8    | 2000 | 367.0       | 367.0      | 35.0        |
| TPS2812DR                   | SOIC         | D               | 8    | 2500 | 340.5       | 338.1      | 20.6        |
| TPS2812DR                   | SOIC         | D               | 8    | 2500 | 367.0       | 367.0      | 35.0        |
| TPS2812PWR                  | TSSOP        | PW              | 8    | 2000 | 367.0       | 367.0      | 35.0        |
| TPS2813DR                   | SOIC         | D               | 8    | 2500 | 340.5       | 338.1      | 20.6        |
| TPS2813DR                   | SOIC         | D               | 8    | 2500 | 367.0       | 367.0      | 38.0        |
| TPS2813PWR                  | TSSOP        | PW              | 8    | 2000 | 367.0       | 367.0      | 35.0        |
| TPS2814DR                   | SOIC         | D               | 8    | 2500 | 367.0       | 367.0      | 35.0        |
| TPS2814DR                   | SOIC         | D               | 8    | 2500 | 340.5       | 338.1      | 20.6        |
| TPS2814PWR                  | TSSOP        | PW              | 8    | 2000 | 367.0       | 367.0      | 35.0        |
| TPS2815DR                   | SOIC         | D               | 8    | 2500 | 340.5       | 338.1      | 20.6        |
| TPS2815PWR                  | TSSOP        | PW              | 8    | 2000 | 367.0       | 367.0      | 35.0        |

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
   E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



# **PW0008A**



# **PACKAGE OUTLINE**

# TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



# PW0008A

# **EXAMPLE BOARD LAYOUT**

# TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# PW0008A

# **EXAMPLE STENCIL DESIGN**

# TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



<sup>8.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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